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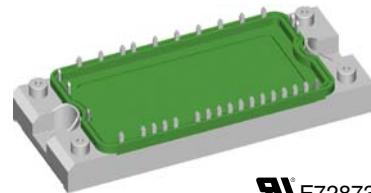
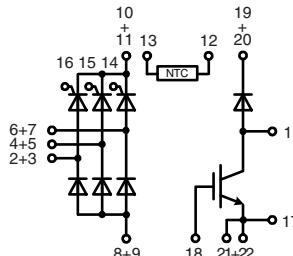
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Three Phase Rectifier Bridge with IGBT and Fast Recovery Diode for Braking System

| V_{RRM} | Type |
|-----------|-----------------|
| V | |
| 1600 | VVZB 135-16 NO1 |



E72873

See outline drawing for pin arrangement

| Symbol | Conditions | Maximum Ratings | | |
|----------------|---|-----------------|------------------------|--|
| V_{RRM} | | 1600 | V | |
| I_{dAVM} | $T_c = 85^\circ\text{C}$; sinusoidal 120° | 135 | A | |
| I_{FSM} | $T_{VJ} = 45^\circ\text{C}$; $t = 10 \text{ ms}$; $V_R = 0 \text{ V}$ $T_{VJ} = 150^\circ\text{C}$; $t = 10 \text{ ms}$; $V_R = 0 \text{ V}$ | 700 | A | |
| I^2t | $T_{VJ} = 45^\circ\text{C}$; $t = 10 \text{ ms}$; $V_R = 0 \text{ V}$ $T_{VJ} = 150^\circ\text{C}$; $t = 10 \text{ ms}$; $V_R = 0 \text{ V}$ | 2450 | A^2s | |
| P_{tot} | $T_c = 25^\circ\text{C}$ per diode | 190 | W | |
| $(di/dt)_{cr}$ | Rectifier Bridge $T_{VJ} = T_{VJM}$; repetitive; $I_T = 150 \text{ A}$ $f = 50 \text{ Hz}$; $t_p = 200 \mu\text{s}$ | 100 | $\text{A}/\mu\text{s}$ | |
| | $V_D = \frac{2}{3} V_{DRM}$; $I_G = 0.45 \text{ A}$; non repetitive; $I_T = I_{d(AV)}/3$ $di_G/dt = 0.45 \text{ A}/\mu\text{s}$ | 500 | $\text{A}/\mu\text{s}$ | |
| $(dv/dt)_{cr}$ | $T_{VJ} = T_{VJM}$; $V_{DR} = \frac{2}{3} V_{DRM}$; $R_{GK} = \infty$; method 1 (linear voltage rise) | 1000 | $\text{V}/\mu\text{s}$ | |
| P_{GM} | $T_{VJ} = T_{VJM}$; $t_p = 30 \mu\text{s}$ $I_T = I_{d(AV)}/3$; $t_p = 300 \mu\text{s}$ | 10 | W | |
| | | 5 | W | |
| P_{GAVM} | | 0.5 | W | |
| V_{CES} | $T_{VJ} = 25^\circ\text{C}$ to 150°C | 1200 | V | |
| V_{GE} | Continuous | ± 20 | V | |
| I_{C25} | $T_c = 25^\circ\text{C}$; DC | 95 | A | |
| I_{C80} | $T_c = 80^\circ\text{C}$; DC | 67 | A | |
| I_{CM} | $t_p = \text{Pulse width limited by } T_{VJM}$ | 100 | A | |
| P_{tot} | $T_c = 25^\circ\text{C}$ | 380 | W | |
| V_{RRM} | | 1200 | V | |
| I_{FAV} | $T_c = 80^\circ\text{C}$; rectangular $d = 0.5$ | 27 | A | |
| I_{FRMS} | $T_c = 80^\circ\text{C}$; rectangular $d = 0.5$ | 38 | A | |
| I_{FRM} | $T_c = 80^\circ\text{C}$; $t_p = 10 \mu\text{s}$; $f = 5 \text{ kHz}$ | tbd | A | |
| I_{FSM} | $T_{VJ} = 45^\circ\text{C}$; $t = 10 \text{ ms}$ | 200 | A | |
| P_{tot} | $T_c = 25^\circ\text{C}$ | 130 | W | |

Data according to IEC 60747

Features

- Soldering connections for PCB mounting
- Convenient package outline
- Thermistor
- Isolation voltage 2500 V~

Applications

- Drive Inverters with brake system

Advantages

- 2 functions in one package
- Easy to mount with two screws
- Suitable for wave soldering
- High temperature and power cycling capability

Recommended replacement:

VVZB 135-16ioXT

| Symbol | Conditions | Characteristic Values ($T_{VJ} = 25^\circ C$, unless otherwise specified) | | |
|--|--|--|----------------------|------|
| | | min. | typ. | max. |
| I_R, I_D | $V_R = V_{RRM}; T_{VJ} = 25^\circ C$ $V_R = V_{RRM}; T_{VJ} = 150^\circ C$ | | 0.1 mA 20 mA | |
| V_F, V_T | $I_F = 80 A; T_{VJ} = 25^\circ C$ | | 1.43 V | |
| V_{TO} r_T | for power-loss calculations only $T_{VJ} = 150^\circ C$ | | 0.85 V 7.1 mΩ | |
| V_{GT} | $V_D = 6 V; T_{VJ} = 25^\circ C$ $T_{VJ} = -40^\circ C$ | | 1.5 V 1.6 V | |
| I_{GT} | $V_D = 6 V; T_{VJ} = 25^\circ C$ $T_{VJ} = -40^\circ C$ | | 78 mA 200 mA | |
| V_{GD} I_{GD} | $T_{VJ} = T_{VJM}; V_D = \frac{2}{3} V_{DRM}$ $T_{VJ} = T_{VJM}; V_D = \frac{2}{3} V_{DRM}$ | | 0.2 V 5 mA | |
| I_L | $V_D = 6 V; t_g = 10 \mu s;$ $di_G/dt = 0.45 A/\mu s; I_G = 0.45 A$ | | 450 mA | |
| I_H | $T_{VJ} = T_{VJM}; V_D = 6 V; R_{GK} = \infty$ | | 100 mA | |
| t_{gd} | $V_D = \frac{1}{2} V_{DRM};$ $di_G/dt = 0.45 A/\mu s; I_G = 0.45 A$ | | 2 μs | |
| t_q | $T_{VJ} = T_{VJM}; V_R = 100 V;$ $V_D = \frac{2}{3} V_{DRM}; t_p = 200 \mu s;$ $dv/dt = 15 V/\mu s; I_T = 20 A;$ $-di/dt = 10 A/\mu s$ | | 150 μs | |
| R_{thJC} R_{thCH} | per diode | 0.2 | 0.65 K/W K/W | |
| $V_{BR(CES)}$ $V_{GE(th)}$ | $V_{GS} = 0 V; I_C = 0.1 mA$ $I_C = 8 mA$ | 1200 4.5 | V 6.45 V | |
| I_{CES} | $V_{CE} = 1200 V; T_{VJ} = 25^\circ C$ $V_{CE} = 0.8 \cdot V_{CES}; T_{VJ} = 125^\circ C$ | | 0.1 mA 0.5 mA | |
| V_{CEsat} | $V_{GE} = 15 V; I_C = 100 A$ | | 3.5 V | |
| $t_{SC} (SCSOA)$ | $V_{GE} = 15 V; V_{CE} = 900 V; T_{VJ} = 125^\circ C$ | | 10 μs | |
| $RBSOA$ | $V_{GE} = 15 V; V_{CE} = 1200 V; T_{VJ} = 125^\circ C;$ clamped inductive load; $L = 100 \mu H$; $R_G = 22 \Omega$ | | 100 A | |
| C_{ies} | $V_{CE} = 25 V; f = 1 MHz, V_{GE} = 0 V$ | 3.8 | nF | |
| $t_{d(on)}$ $t_{d(off)}$ E_{on} E_{off} | $\left\{ \begin{array}{l} V_{CE} = 720 V; I_C = 50 A \\ V_{GE} = 15 V; R_G = 22 \Omega \\ \text{Inductive load; } L = 100 \mu H \\ T_{VJ} = 125^\circ C \end{array} \right.$ | 150 680 6 5 | ns ns mJ mJ | |
| R_{thJC} R_{thCH} | | 0.1 | 0.33 K/W K/W | |

| Symbol | Conditions | Characteristic Values | | |
|-------------|--|---|------|----------------|
| | | $(T_{VJ} = 25^\circ\text{C}, \text{unless otherwise specified})$ | | |
| | | min. | typ. | max. |
| I_R | $V_R = V_{RRM}; T_{VJ} = 25^\circ\text{C}$ $V_R = 1200 \text{ V}; T_{VJ} = 125^\circ\text{C}$ | | 1 | 0.25 mA mA |
| V_F | $I_F = 30 \text{ A}; T_{VJ} = 25^\circ\text{C}$ | | | 2.76 V |
| V_{TO} | For power-loss calculations only | | | 1.3 V |
| r_T | $T_{VJ} = 150^\circ\text{C}$ | | | 16 mΩ |
| I_{RM} | $I_F = 50 \text{ A}; -di_F/dt = 100 \text{ A}/\mu\text{s}; V_R = 100 \text{ V}$ | 5.5 | 11 A | |
| t_{rr} | $I_F = 1 \text{ A}; -di_F/dt = 200 \text{ A}/\mu\text{s}; V_R = 30 \text{ V}$ | 40 | | ns |
| R_{thJC} | | | 0.25 | 0.9 K/W K/W |
| R_{thCH} | | | | |
| R_{25} | NTC | $\left\{ R(T) = R_{25} \cdot e^{B_{25/100} \left(\frac{1}{T} - \frac{1}{298K} \right)} \right\}$ | 4.75 | 5.0 kΩ |
| $B_{25/50}$ | | | | 5.25 kΩ K |

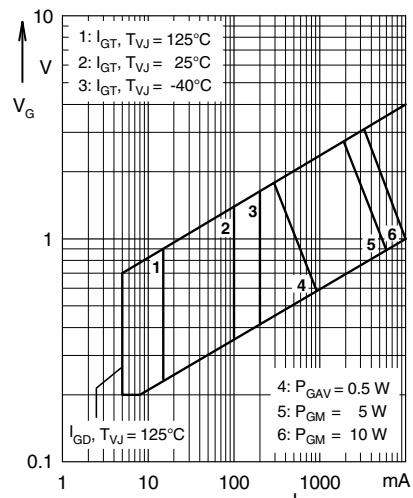


Fig. 1 Gate trigger characteristics

| Symbol | Conditions | Maximum Ratings | | |
|------------|--|--------------------|--|----------------|
| T_{VJ} | | -40...+150 | | °C |
| T_{VJM} | | 150 | | °C |
| T_{stg} | | -40...+125 | | °C |
| V_{ISOL} | 50/60 Hz; $t = 1 \text{ min}$ $I_{ISOL} \leq 1 \text{ mA}; t = 1 \text{ s}$ | 2500 V~ 3000 V~ | | |
| M_d | Mounting torque | 2.7...3.3 | | Nm |
| d_s | Creep distance on surface | 12.7 | | mm |
| d_A | Strike distance in air | 9.6 | | mm |
| a | Maximum allowable acceleration | 50 | | m/s^2 |
| Weight | typ. | 180 | | g |

Dimensions in mm (1 mm = 0.0394")

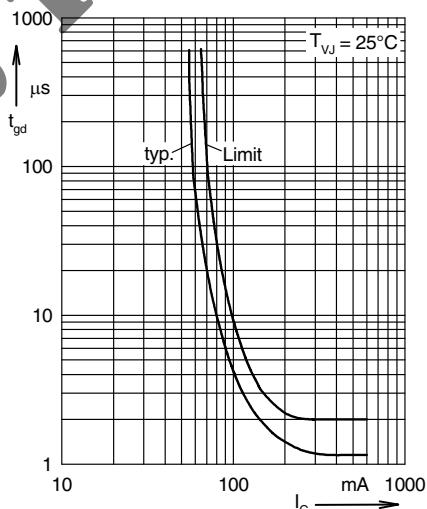
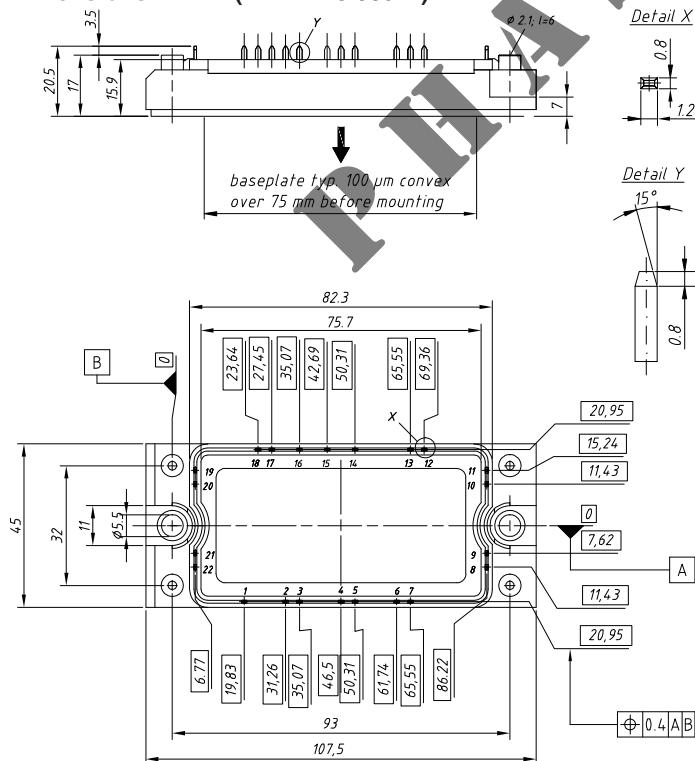


Fig. 2 Gate trigger delay time

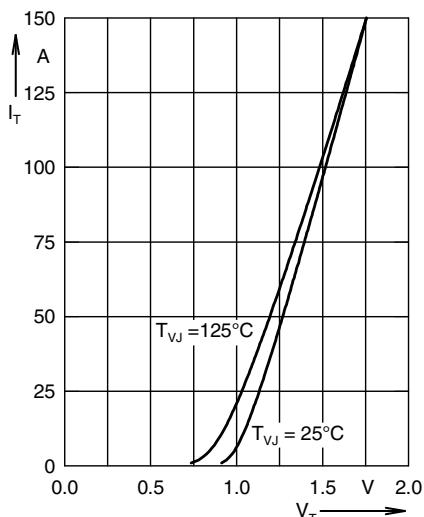


Fig. 3 Forward current versus voltage drop per leg

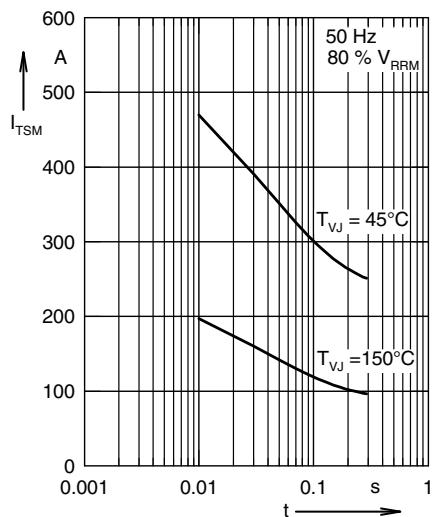


Fig. 4 Surge overload current

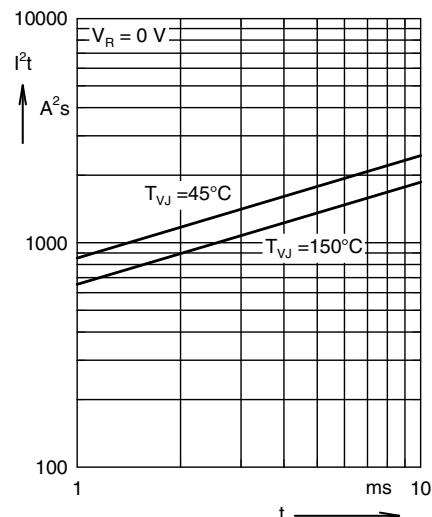
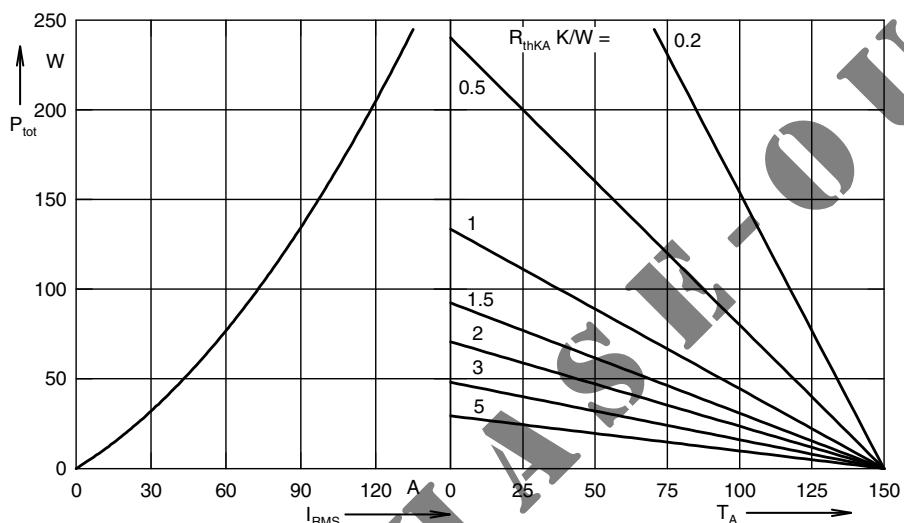
Fig. 5 I^2t versus time (per thyristor/diode)

Fig. 6 Power dissipation versus direct output current and ambient temperature

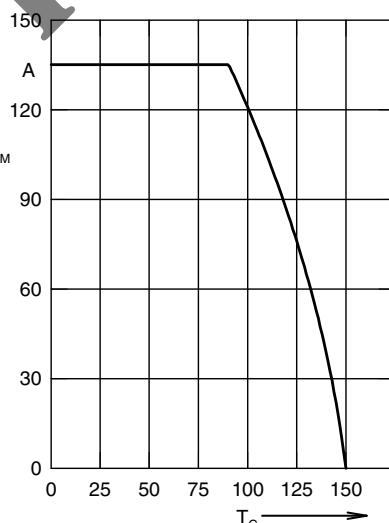


Fig. 7 Maximum forward current at case temperature

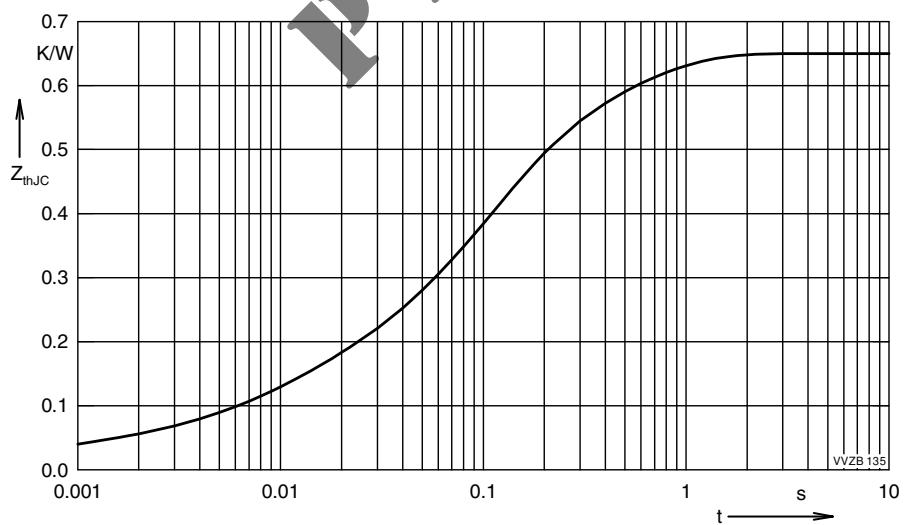


Fig. 8 Transient thermal impedance junction to case (per thyristor/diode)

| Constants for Z_{thJC} calculation: | |
|---------------------------------------|--------------------|
| $R_{thi} / (\text{K/W})$ | $t_i / (\text{s})$ |
| 0.03 | 0.0005 |
| 0.083 | 0.008 |
| 0.361 | 0.094 |
| 0.176 | 0.45 |

